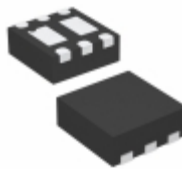
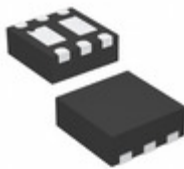

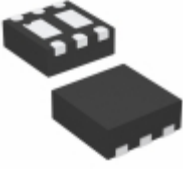
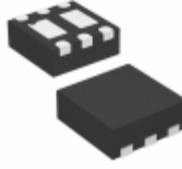
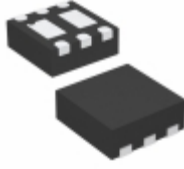
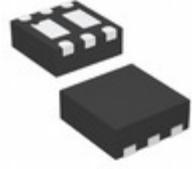
	<h2>SIA923AEDJ-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIA923AEDJ-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2P-CH 20V 4.5A SC70-6L</p> <p>Datenblätter: 1.SIA923AEDJ-T1-GE3.pdf 2.SIA923AEDJ-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 791 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA923AEDJ-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 20V 4.5A SC70-6L
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	791 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	7.8W
Verpackung / Gehäuse	PowerPAK® SC-70-6 Dual
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Dual
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A
Rds On (Max) @ Id, Vgs	54 mOhm @ 3.8A, 4.5V
VGS (th) (Max) @ Id	900mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	770pF @ 10V
Verpackung	Original-Reel®

SIA923AEDJ-T1-GE3 ist neu im Original, Suche SIA923AEDJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA923AEDJ-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIA923AEDJ-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIA922EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 4.5A SC70-6</p>	 <p>SIA921EDJ-T4-GE3 Vishay / Siliconix MOSFET 2P-CH 20V 4.5A SC70-6</p>	 <p>SIA921EDJ-T4-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 4.5A SC70-6</p>	 <p>SIA923EDJ-T1-GE3CT Vishay Precision Group SIA923EDJ-T1-GE3CT VISHAY</p>
 <p>SIA928DJ-T1-GE3 Vishay / Siliconix MOSFET ARRAY 2N-CH 30V SC70-6</p>	 <p>SIA923EDJ-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 20V 4.5A SC-70-6</p>	 <p>SIA922EDJ-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 4.5A SC70-6</p>	 <p>SIA923EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 4.5A SC-70-6</p>

heiße Teile

Mehr

⊛ SIA906EDJ-T1-GE3	↔ SIA906EDJ-T1-GE3	↔ SIA906EDJ-T4-GE3	D SIA907EDJT	↔ SIA907EDJT-T1-GE3
⊣ SIA907EDJT-T1-GE3	⊛ SIA907EDJT-T4-GE3	D SIA910EDJ-T1-GE3	↔ SIA910EDJ-T1-GE3	↔ SIA911ADJ-T1-GE3
⊛ SIA911ADJ-T1-GE3	⊣ SIA911ADJ-T5-GE3	⊛ SIA911DJ-T1-E3	↔ SIA911DJ-T1-E3	↔ SIA911DJ-T1-GE3
D SIA911DJ-T1-GE3	⊛ SIA911DJ-T5-GE3	⊣ SIA911EDJ-T1-GE3	⊛ SIA911EDJ-T1-GE3	↔ SIA912DJ
↔ SIA912DJ-T1-GE3	↔ SIA912DJ-T1-GE3	⊛ SIA913ADJ-T1-GE3	⊣ SIA913ADJ-T1-GE3	↔ SIA913DJ-T1-GE3
↔ SIA913DJ-T1-GE3	↔ SIA914ADJ-T1-GE3	D SIA914ADJ-T1-GE3	⊛ SIA914DJ-T1-GE3	⊣ SIA914DJ-T1-GE3
⊛ SIA915DJ-T1-GE3	D SIA915DJ-T1-GE3	↔ SIA917DJ-T1-GE3	↔ SIA917DJ-T1-GE3	↔ SIA920DJ-T1-GE3
⊣ SIA920DJ-T1-GE3	⊛ SIA921EDJ-T1-GE3	↔ SIA921EDJ-T1-GE3	↔ SIA921EDJ-T1/GE3	↔ SIA922EDJ-T1-GE3
⊛ SIA922EDJ-T1-GE3	⊣ SIA923AEDJ-T1-GE3	⊛ SIA923EDJ-T1-GE3	D SIA923EDJ-T1-GE3	↔ SIA929DJ-T1-GE3
↔ SIA929DJ-T1-GE3	⊛ SIA931DJ-T1-GE3	⊣ SIA931DJ-T1-GE3	⊛ SIA975DJ-T1-GE3	↔ SIA975DJ-T1-GE3

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